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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, FlexIO, I²C, LINbus, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	89
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b SAR; D/A1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k144hrt0vllr

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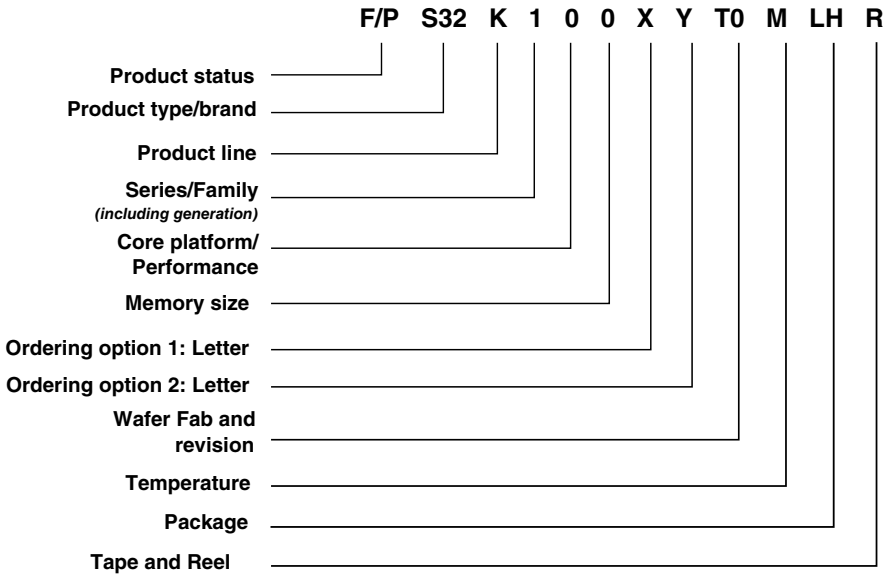
3 Ordering information

3.1 Selecting orderable part number

Not all part number combinations are available. See the attachment *S32K1xx_Orderable_Part_Number_ List.xlsx* attached with the Datasheet for a list of standard orderable part numbers.

3.2 Ordering information



Product status
P: Prototype
F: Qualified

Product type/brand
S32: Automotive 32-bit MCU

Product line
K: Arm Cortex MCUs

Series/Family
1: 1st product series
2: 2nd product series

Core platform/Performance
1: Arm Cortex M0+
4: Arm Cortex M4F

Memory size

	2	4	6	8
S32K11x			128K	256K
S32K14x	256K	512K	1M	2M

Ordering option
X: Speed
B: 48 MHz without DMA (S32K11x only)
L: 48 MHz with DMA (S32K11x only)
H: 80 MHz
U[1]: 112 MHz (Not valid with M temperature/125C)

Y: Optional feature
R: Base feature set
F: CAN FD, FlexIO
A[1]: CAN FD, FlexIO, Security
E: Ethernet, Serial Audio Interface (S32K148 only)
J[1]: Ethernet, Serial Audio Interface, CAN FD, FlexIO, Security (S32K148 only)

Wafer, Fab and revision
Fx: ATMC[2]
Tx: GF
XX: Flex #[2]

x0: 1st revision

Temperature
V: -40C to 105C
M: -40C to 125C
W: -40C to 150C[2]

Package

Pins	LQFP	QFN	BGA
32	-	FM	-
48	LF	-	-
64	LH	-	-
100	LL	-	MH
144	LQ	-	-
176	LU	-	-

Tape and Reel
T: Trays/Tubes
R: Tape and Reel

1. CSEc (Security) or EEPROM writes/erase will trigger error flags in HSRUN mode (112 MHz) because this use case is not allowed to execute simultaneously. The device will need to switch to RUN mode (80 MHz) to execute CSEc (Security) or EEPROM writes/erase.
2. Not supported yet
3. Part numbers no longer offered as standard include:
   Ordering Option X (M:64MHz); Ordering Option Y (N: limited RAM. 16KB for K142, 48KB for K144, 96KB for K146, 192KB for K148 S: Security); Temperature (C: -40C to 85C)

NOTE
Not all part number combinations are available. See S32K1xx_Orderable_Part_Number_List.xlsx attached with the Datasheet for list of standard orderable parts.

Figure 4. Ordering information

5. V_{REFH} should always be equal to or less than V_{DDA} + 0.1 V and V_{DD} + 0.1 V
6. Open drain outputs must be pulled to V_{DD}.
7. When input pad voltage levels are close to V_{DD} or V_{SS}, practically no current injection is possible.

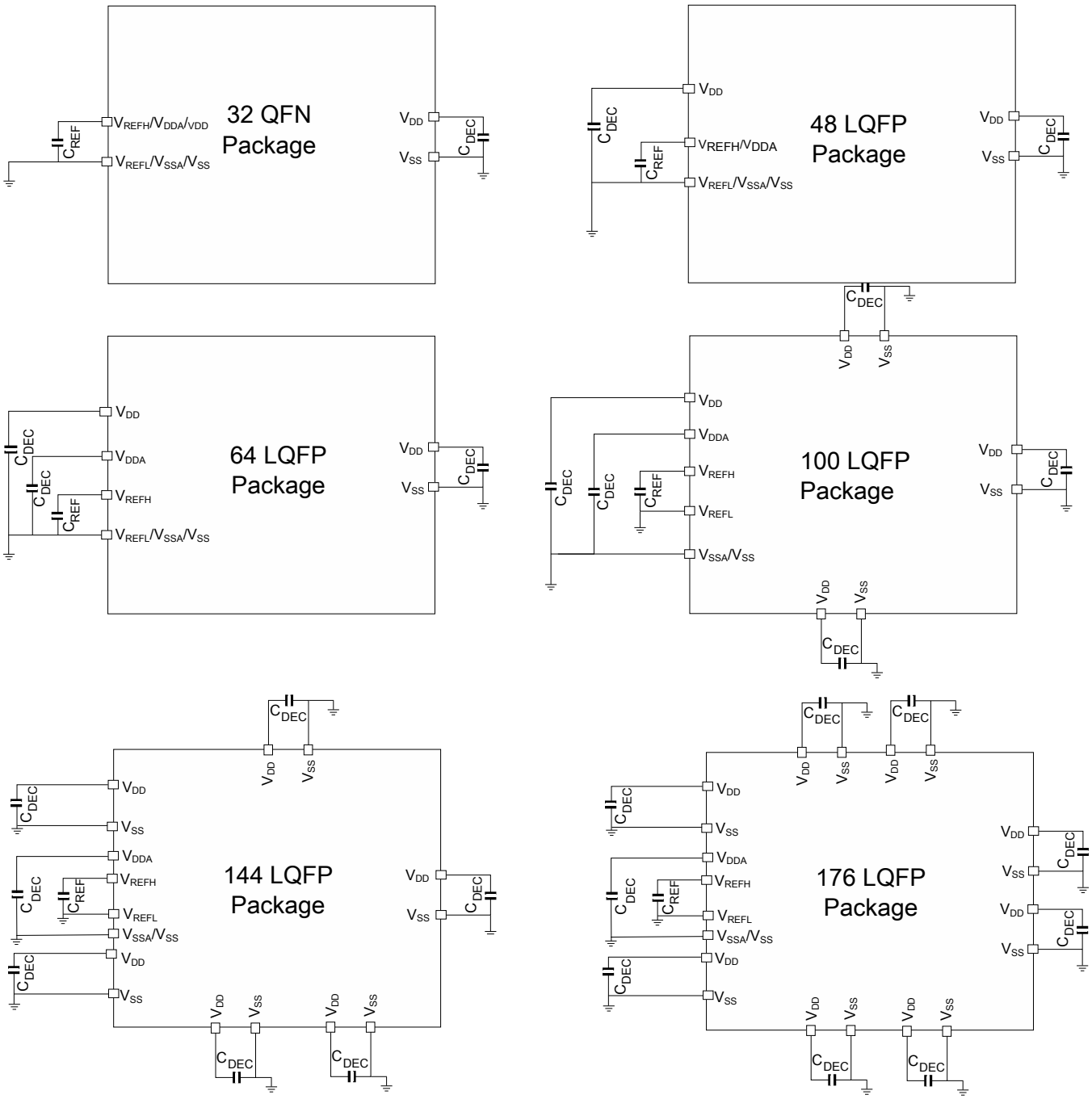
4.3 Thermal operating characteristics

Table 3. Thermal operating characteristics for 64 LQFP, 100 LQFP, and 100 MAP-BGA packages.

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$T_{A\ C\text{-}Grade\ Part}$	Ambient temperature under bias	–40	—	85[1]	℃
$T_{J\ C\text{-}Grade\ Part}$	Junction temperature under bias	–40	—	105[1]	℃
$T_{A\ V\text{-}Grade\ Part}$	Ambient temperature under bias	–40	—	105[1]	℃
$T_{J\ V\text{-}Grade\ Part}$	Junction temperature under bias	–40	—	125[1]	℃
$T_{A\ M\text{-}Grade\ Part}$	Ambient temperature under bias	–40	—	125[2]	℃
$T_{J\ M\text{-}Grade\ Part}$	Junction temperature under bias	–40	—	135[2]	℃

1. Values mentioned are measured at ≤ 112 MHz in HSRUN mode.
2. Values mentioned are measured at ≤ 80 MHz in RUN mode.

4.4 Power and ground pins



NOTE: V_{DD} and V_{DDA} must be shorted to a common source on PCB

Figure 5. Pinout decoupling

Table 4. Supplies decoupling capacitors 1, 2

Symbol	Description	Min. 3	Typ.	Max.	Unit
C_{REF}, 4, 5	ADC reference high decoupling capacitance	70	100	—	nF
C_{DEC} 5, 6, 7	Recommended decoupling capacitance	70	100	—	nF

1. V_{DD} and V_{DDA} must be shorted to a common source on PCB. The differential voltage between V_{DD} and V_{DDA} is for RF-AC only. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note AN5032 for reference supply design for SAR ADC. All V_{SS} pins should be connected to common ground at the PCB level.
2. All decoupling capacitors must be low ESR ceramic capacitors (for example X7R type).
3. Minimum recommendation is after considering component aging and tolerance.
4. For improved performance, it is recommended to use 10 µF, 0.1 µF and 1 nF capacitors in parallel.
5. All decoupling capacitors should be placed as close as possible to the corresponding supply and ground pins.
6. Contact your local Field Applications Engineer for details on best analog routing practices.
7. The filtering used for decoupling the device supplies must comply with the following best practices rules:
   - The protection/decoupling capacitors must be on the path of the trace connected to that component.
   - No trace exceeding 1 mm from the protection to the trace or to the ground.
   - The protection/decoupling capacitors must be as close as possible to the input pin of the device (maximum 2 mm).
   - The ground of the protection is connected as short as possible to the ground plane under the integrated circuit.

5. Several I/O have both high drive and normal drive capability selected by the associated Portx_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *SK3K144_IO_Signal_Description_Input_Multiplexing.xlsx* attached with the *Reference Manual*.
6. Measured at input V = V_{SS}
7. Measured at input V = V_{DD}

5.5 AC electrical specifications at 3.3 V range

Table 13. AC electrical specifications at 3.3 V Range

Symbol	DSE	Rise time (nS) [1]		Fall time (nS) [1]		Capacitance (pF) [2]
		Min.	Max.	Min.	Max.	
tRF_{GPIO}	NA	3.2	14.5	3.4	15.7	25
		5.7	23.7	6.0	26.2	50
		20.0	80.0	20.8	88.4	200
$tRF_{GPIO-HD}$	0	3.2	14.5	3.4	15.7	25
		5.7	23.7	6.0	26.2	50
		20.0	80.0	20.8	88.4	200
	1	1.5	5.8	1.7	6.1	25
		2.4	8.0	2.6	8.3	50
		6.3	22.0	6.0	23.8	200
$tRF_{GPIO-FAST}$	0	0.6	2.8	0.5	2.8	25
		3.0	7.1	2.6	7.5	50
		12.0	27.0	10.3	26.8	200
	1	0.4	1.3	0.38	1.3	25
		1.5	3.8	1.4	3.9	50
		7.4	14.9	7.0	15.3	200

1. For reference only. Run simulations with the IBIS model and your custom board for accurate results.
2. Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

5.6 AC electrical specifications at 5 V range

Table 14. AC electrical specifications at 5 V Range

Symbol	DSE	Rise time (nS)[1]		Fall time (nS) [1]		Capacitance (pF) [2]
		Min.	Max .	Min.	Max.	
tRF_{GPIO}	NA	2.8	9.4	2.9	10.7	25
		5.0	15.7	5.1	17.4	50
		17.3	54.8	17.6	59.7	200
$tRF_{GPIO-HD}$	0	2.8	9.4	2.9	10.7	25
		5.0	15.7	5.1	17.4	50

Table continues on the next page...

Table 16. Device clock specifications [1] (continued)

Symbol	Description	Min.	Max.	Unit
f_{FLASH}	Flash clock	—	24	MHz
Normal run mode (S32K14x series) [3]				
f_{SYS}	System and core clock	—	80	MHz
f_{BUS}	Bus clock	—	40[4]	MHz
f_{FLASH}	Flash clock	—	26.67	MHz
VLPR mode[5]				
f_{SYS}	System and core clock	—	4	MHz
f_{BUS}	Bus clock	—	4	MHz
f_{FLASH}	Flash clock	—	1	MHz
f_{ERCLK}	External reference clock	—	16	MHz

1. Refer to the section Feature comparison for the availability of modes and other specifications.
2. Only available on some devices. See section Feature comparison.
3. With SPLL as system clock source.
4. 48 MHz when f_{SYS} is 48 MHz
5. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

6 Peripheral operating requirements and behaviors

6.1 System modules

There are no electrical specifications necessary for the device's system modules.

6.2 Clock interface modules

6.2.1 External System Oscillator electrical specifications

Table 23. Flash command timing specifications for S32K14x (continued)

Symbol	Description[1]		S32K142		S32K144		S32K146		S32K148			
			Typ	Max	Typ	Max	Typ	Max	Typ	Max	Unit	Notes
t_{setram}	Set FlexRAM Function execution time	Control Code 0xFF	0.08	—	0.08	—	0.08	—	0.08	—	ms	3
		32 KB EEPROM backup	0.8	1.2	0.8	1.2	0.8	1.2	—	—		
		48 KB EEPROM backup	1	1.5	1	1.5	1	1.5	—	—		
		64 KB EEPROM backup	1.3	1.9	1.3	1.9	1.3	1.9	1.3	1.9		
t_{eewr8b}	Byte write to FlexRAM execution time	32 KB EEPROM backup	385	1700	385	1700	385	1700	—	—	µs	3,4
		48 KB EEPROM backup	430	1850	430	1850	430	1850	—	—		
		64 KB EEPROM backup	475	2000	475	2000	475	2000	475	4000		
$t_{eewr16b}$	16-bit write to FlexRAM execution time	32 KB EEPROM backup	385	1700	385	1700	385	1700	—	—	µs	3,4
		48 KB EEPROM backup	430	1850	430	1850	430	1850	—	—		
		64 KB EEPROM backup	475	2000	475	2000	475	2000	475	4000		
$t_{eewr32bers}$	32-bit write to erased FlexRAM location execution time	—	360	2000	360	2000	360	2000	360	2000	µs	
$t_{eewr32b}$	32-bit write to FlexRAM execution time	32 KB EEPROM backup	630	2000	630	2000	630	2000	—	—	µs	3,4
		48 KB EEPROM backup	720	2125	720	2125	720	2125	—	—		
		64 KB EEPROM backup	810	2250	810	2250	810	2250	810	4500		
$t_{quickwr}$	32-bit Quick Write execution time: Time from CCIF clearing (start the write) until CCIF	1st 32-bit write	200	550	200	550	200	550	200	1100	µs	4,5,6
		2nd through Next to Last (Nth-1) 32-bit write	150	550	150	550	150	550	150	550		

Table continues on the next page...

Table 26. QuadSPI electrical specifications (continued)

FLASH PORT	Sym	Unit	FLASH A												FLASH B			
			RUN[1]						HSRUN[1]						RUN/HSRUN[2]			
QuadSPI Mode			SDR						SDR						SDR		DDR[3]	
			Internal Sampling		Internal DQS				Internal Sampling		Internal DQS				Internal Sampling		External DQS	
			N1		PAD Loopback		Internal Loopback		N1		PAD Loopback		Internal Loopback		N1		External DQS	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
SCK Duty Cycle	t_{SDC}	ns	tSCK/2 - 1.5	tSCK/2 + 1.5	tSCK/2 - 1.5	tSCK/2 + 1.5	tSCK/2 - 1.5	tSCK/2 + 1.5	tSCK/2 - 1.5	tSCK/2 + 1.5	tSCK/2 - 0.750	tSCK/2 - 0.750	tSCK/2 - 1.5	tSCK/2 + 1.5	tSCK/2 - 2.5	tSCK/2 + 2.5	tSCK/2 - 2.5	tSCK/2 + 2.5
Data Input Setup Time	t_{IS}	ns	15	-	2.5	-	10	-	14	-	1.6	-	9	-	25	-	2	-
Data Input Hold Time	t_{IH}	ns	0	-	1	-	1	-	0	-	1	-	1	-	0	-	20	-
Data Output Valid Time	t_{OV}	ns	-	4.5	-	4.5	-	4.5	-	4	-	4	-	4	-	10	-	10
Data Output In-Valid Time	t_{IV}	ns	-	5	-	5	-	5	-	5	-	3[5]	-	5	-	5	5	-
CS to SCK Time [6]	t_{CSSCK}	ns	5	-	5	-	5	-	5	-	5	-	5	-	10	-	10	-
SCK to CS Time [7]	t_{SCKCS}	ns	5	-	5	-	5	-	5	-	5	-	5	-	5	-	5	-
Output Load		pf	25		25		25		25		25		25		25		25	

1. See Reference Manual for details on mode settings
2. See Reference Manual for details on mode settings
3. Valid for HyperRAM only
4. RWDS(External DQS CLK) frequency
5. For operating frequency ≤ 64 Mhz,Output invalid time is 5 ns.
6. Program register value QuadSPI_FLSHCR[TCSS] = 4`h2
7. Program register value QuadSPI_FLSHCR[TCSH] = 4`h1

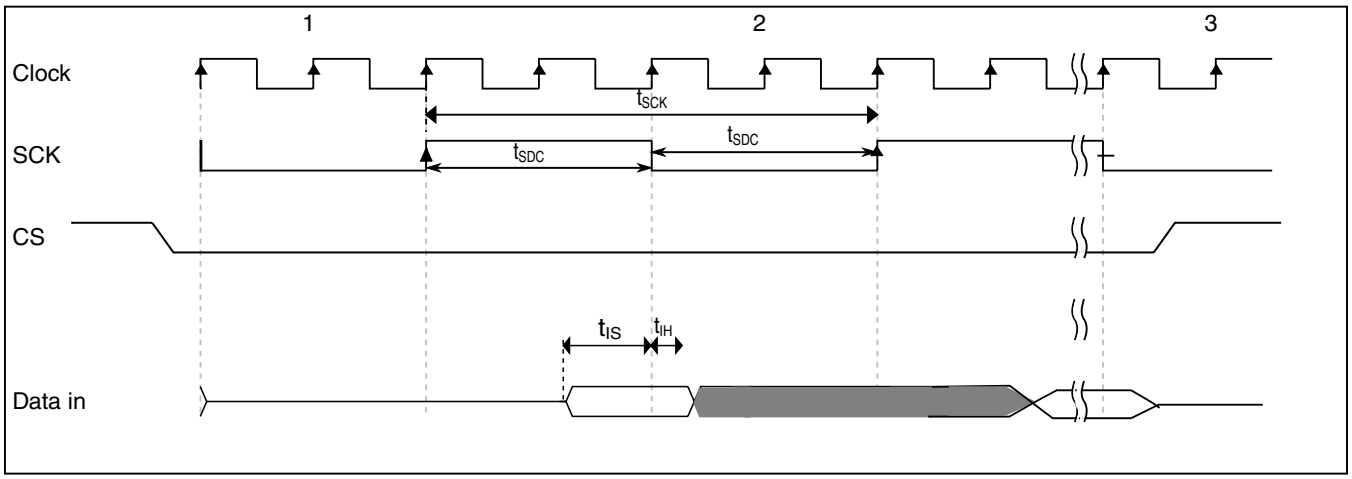


Figure 9. QuadSPI input timing (SDR mode) diagram

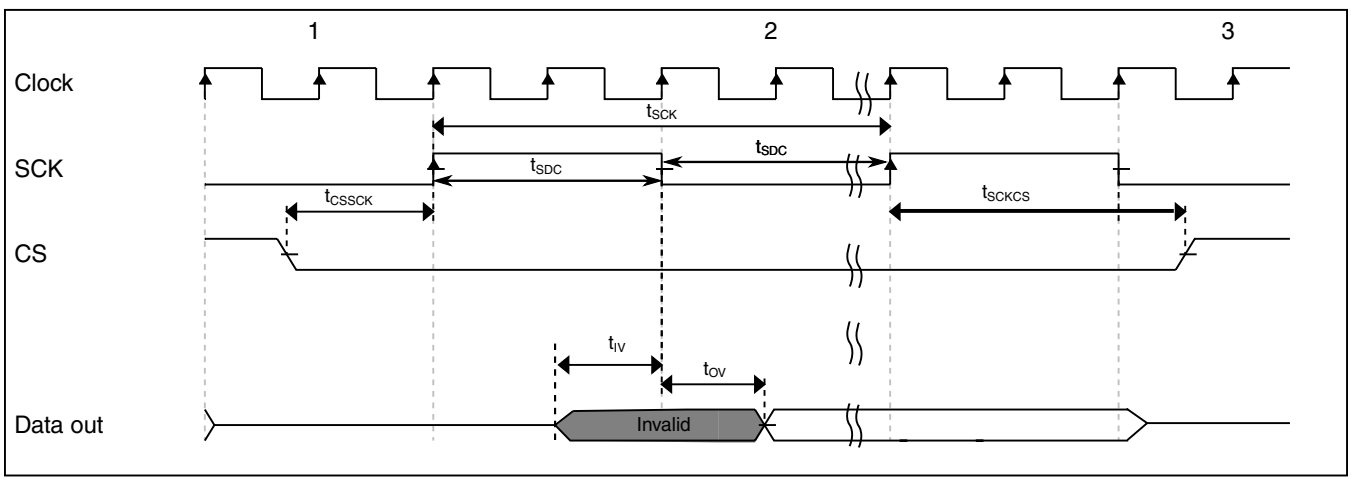
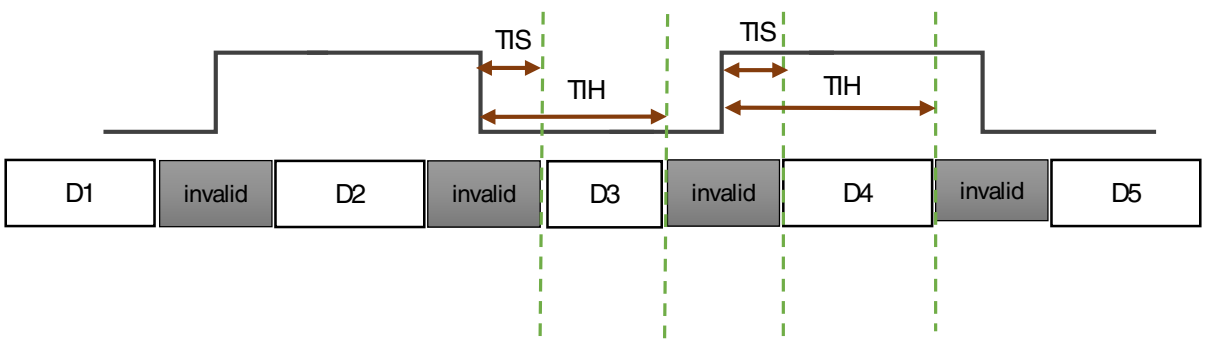


Figure 10. QuadSPI output timing (SDR mode) diagram



TIS – Setup Time
TIH – Hold Time

Figure 11. QuadSPI input timing (HyperRAM mode) diagram

Table 27. 12-bit ADC operating conditions (continued)

Symbol	Description	Conditions	Min.	Typ.[1]	Max.	Unit	Notes
f_{ADCK}	ADC conversion clock frequency	Normal usage	2	40	50	MHz	3, 4
f_{CONV}	ADC conversion frequency	No ADC hardware averaging.[5] Continuous conversions enabled, subsequent conversion time	46.4	928	1160	Ksps	6, 7
		ADC hardware averaging set to 32. [5] Continuous conversions enabled, subsequent conversion time	1.45	29	36.25	Ksps	6, 7

1. Typical values assume V_{DDA} = 5 V, Temp = 25 °C, f_{ADCK} = 40 MHz, R_{AS}=20 Ω, and C_{AS}=10 nF unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. For packages without dedicated V_{REFH} and V_{REFL} pins, V_{REFH} is internally tied to V_{DDA}, and V_{REFL} is internally tied to V_{SS}. To get maximum performance, reference supply quality should be better than SAR ADC. See application note AN5032 for details.
3. Clock and compare cycle need to be set according to the guidelines mentioned in the *Reference Manual* .
4. ADC conversion will become less reliable above maximum frequency.
5. When using ADC hardware averaging, see the *Reference Manual* to determine the most appropriate setting for AVGS.
6. Numbers based on the minimum sampling time of 275 ns.
7. For guidelines and examples of conversion rate calculation, see the *Reference Manual* section 'Calibration function'

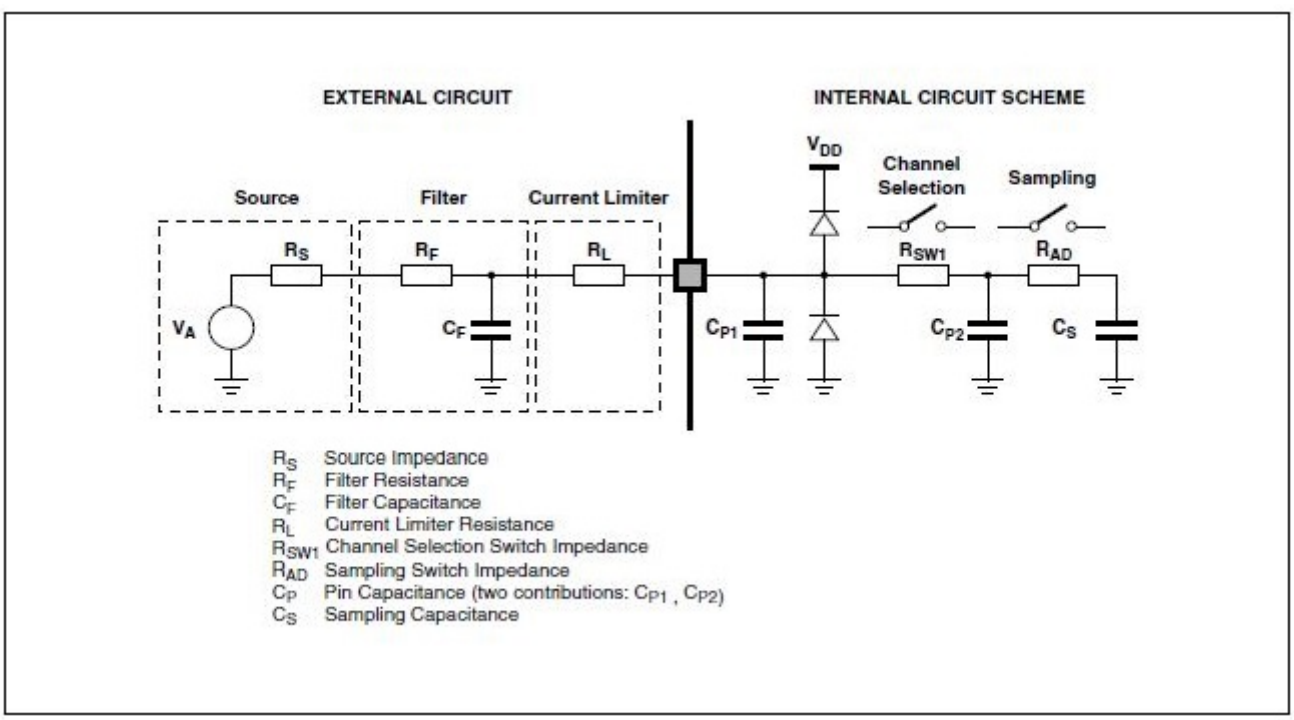


Figure 13. ADC input impedance equivalency diagram

Table 31. Comparator with 8-bit DAC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit
	Analog comparator hysteresis, Hyst2, Low-speed mode				
	-40 - 125 °C	—	23	80	
V_{HYST3}	Analog comparator hysteresis, Hyst3, High-speed mode				mV
	-40 - 125 °C	—	46	200	
	Analog comparator hysteresis, Hyst3, Low-speed mode				
	-40 - 125 °C	—	32	120	
I_{DAC8b}	8-bit DAC current adder (enabled)				
	3.3V Reference Voltage	—	6	9	µA
	5V Reference Voltage	—	10	16	µA
INL[5]	8-bit DAC integral non-linearity	–0.75	—	0.75	LSB[6]
DNL	8-bit DAC differential non-linearity	–0.5	—	0.5	LSB[6]
t_{DDAC}	Initialization and switching settling time	—	—	30	µs

1. Difference at input > 200mV
2. Applied ± (100 mV + $V_{HYST0/1/2/3}$+ max. of V_{AIO}) around switch point.
3. Applied ± (30 mV + 2 × $V_{HYST0/1/2/3}$+ max. of V_{AIO}) around switch point.
4. Applied ± (100 mV + $V_{HYST0/1/2/3}$).
5. Calculation method used: Linear Regression Least Square Method
6. 1 LSB = $V_{reference}$/256

NOTE

For comparator IN signals adjacent to V_{DD}/V_{SS} or XTAL/EXTAL or switching pins cross coupling may happen and hence hysteresis settings can be used to obtain the desired comparator performance. Additionally, an external capacitor (1nF) should be used to filter noise on input signal. Also, source drive should not be weak (Signal with < 50 K pull up/down is recommended).

6.5 Communication modules

6.5.1 LPUART electrical specifications

Refer to General AC specifications for LPUART specifications.

6.5.1.1 Supported baud rate

Baud rate = Baud clock / ((OSR+1) * SBR).

For details, see section: 'Baud rate generation' of the *Reference Manual*.

6.5.2 LPSPI electrical specifications

The Low Power Serial Peripheral Interface (LPSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic LPSPI timing modes.

- All timing is shown with respect to 20% V_{DD} and 80% V_{DD} thresholds.
- All measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew setting (DSE = 1).

Table 32. LPSPI electrical specifications[1] (continued)

Num	Symbol	Description	Conditions	Run Mode[2]				HSRUN Mode[2]				VLPR Mode				Unit
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
8	t_a	Slave access time	Slave	-	50	-	50	-	50	-	50	-	100	-	100	ns
9	t_{dis}	Slave MISO (SOUT) disable time	Slave	-	50	-	50	-	50	-	50	-	100	-	100	ns
10	t_v	Data valid (after SPSCK edge)	Slave	-	30	-	39	-	26	-	36 [11] 31 [12]	-	92	-	96	ns
			Master	-	12	-	16	-	11	-	15	-	47	-	48	
			Master Loopback[5]	-	12	-	16	-	11	-	15	-	47	-	48	
			Master Loopback(slow)[6]	-	8	-	10	-	7	-	9	-	44	-	44	
11	t_{HO}	Data hold time(outputs)	Slave	4	-	4	-	4	-	4	-	4	-	4	-	ns
			Master	-15	-	-22	-	-15	-	-23	-	-22	-	-29	-	
			Master Loopback[5]	-10	-	-14	-	-10	-	-14	-	-14	-	-19	-	
			Master Loopback(slow)[6]	-15	-	-22	-	-15	-	-22	-	-21	-	-27	-	
12	$t_{RI/FI}$	Rise/Fall time input	Slave	-	1	-	1	-	1	-	1	-	1	-	1	ns
			Master	-		-		-		-		-		-		
			Master Loopback[5]	-		-		-		-		-		-		
			Master Loopback(slow)[6]	-		-		-		-		-		-		
13	$t_{RO/FO}$	Rise/Fall time output	Slave	-	25	-	25	-	25	-	25	-	25	-	25	ns
			Master	-		-		-		-		-		-		
			Master Loopback [5]	-		-		-		-		-		-		

Table continues on the next page...

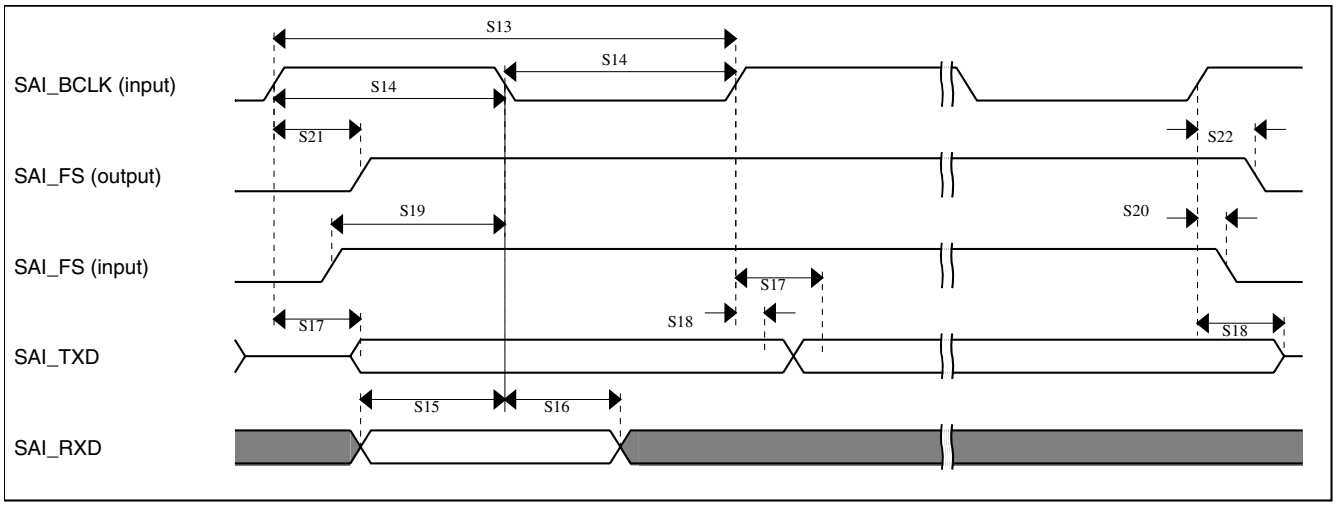


Figure 23. SAI Timing — Slave modes

6.5.6 Ethernet AC specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

The following table describes the MII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.

Table 35. MII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns

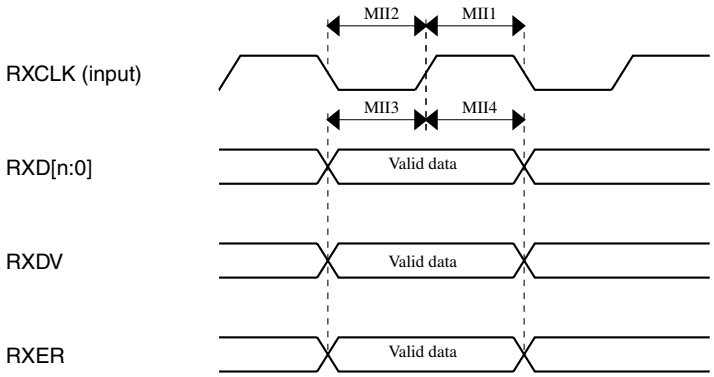


Figure 24. MII receive diagram

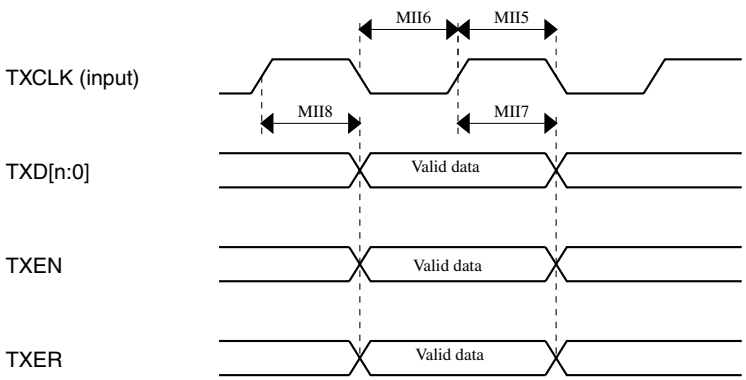


Figure 25. MII transmit signal diagram

The following table describes the RMII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.

Table 36. RMII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RMII input clock RMII_CLK Frequency	—	50	MHz
RMII1, RMII5	RMII_CLK pulse width high	35%	65%	RMII_CLK period
RMII2, RMII6	RMII_CLK pulse width low	35%	65%	RMII_CLK period
RMII3	RXD[1:0], CRS_DV, RXER to RMII_CLK setup	4	—	ns
RMII4	RMII_CLK to RXD[1:0], CRS_DV, RXER hold	2	—	ns

Table continues on the next page...

9 Pinouts

9.1 Package pinouts and signal descriptions

For package pinouts and signal descriptions, refer to the Reference Manual.

10 Revision History

The following table provides a revision history for this document.

Table 43. Revision History

Rev. No.	Date	Substantial Changes
1	12 Aug 2016	Initial release

2	03 March 2017	• Updated descpition of QSPI and Clock interfaces in Key Features section
		• Updated figure: High-level architecture diagram for the S32K1xx family
		• Updated figure: S32K1xx product series comparison
		• Added note in section Selecting orderable part number
		• Updated figure: Ordering information
		• In table: Absolute maximum ratings :
		  • Added footnote to I_{INJPAD_DC}
		  • Updated min and max value of I_{INJPAD_DC}
		  • Updated description, max and min values for I_{INJSUM}
		  • Updated $V_{IN\_TRANSIENT}$
		• In table: Voltage and current operating requirements :
		  • Renamed V_{SUP_OFF}
		  • Updated max value of V_{DD_OFF}
		  • Removed V_{INA} and V_{IN}
		  • Added V_{REFH} and V_{REFL}
		  • Updated footnote "Typical conditions assumes V_{DD} = V_{DDA} = V_{REFH} = 5 V ...
		  • Removed I_{NJSUM_AF}
		• Updated footnotes in table Table 4
		• Updated section Power mode transition operating behaviors
		• In table: Power consumption
		  • Added footnote "With PMC_REGSC[CLKBIASDIS] ... "
		  • Updated conditions for VLPR
		  • Removed Idd/MHz for S32K144
		  • Updated numbers for S32K142 and S32K148
		  • Removed use case footnotes
		• In section Modes configuration :
		  • Replaced table "Modes configuration" with spreadsheet attachment: 'S32K1xx_Power_Modes _Master_configuration_sheet'
		• In table: DC electrical specifications at 3.3 V Range :
		  • Added footnotes to V_{ih} Input Buffer High Voltage and V_{ih} Input Buffer Low Voltage
		  • Added footnote to High drive port pins
		• In table: DC electrical specifications at 5.0 V Range :

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Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		• Updated note 'All the limits defined ... ' • Updated parameter '$I_{INJPAD\_DC\_ABS}$', 'V_{IN_DC}', $I_{INJSUM\_DC\_ABS}$. • In Table 2, • Updated parameter $I_{INJPAD\_DC\_OP}$ and $I_{INJSUM\_DC\_OP}$. • In Table 5, updated TBDs for V_{LVR_HYST}, V_{LVD_HYST}, and $_{VLVW\_HYST}$ • In Power mode transition operating behaviors, • Added VLPR → VLPS • Added VLPS → VLPR • Updated TBDs for VLPS → Asynchronous DMA Wakeup, STOP1 → Asynchronous DMA Wakeup, and STOP2 → Asynchronous DMA Wakeup • In Table 7, updated the specifications for S32K144. • Updated the attachment *S32K1xx_Power_Modes _Configuration.xlsx*. • In Table 15, removed C_{IN_A}. • In Table 17, • Updated specificatins for g_{mXOSC}. • Removed I_{DDOSC} • In Table 19, • Added parameter ΔF125. • Removed I_{DDFIRC} • In Table 20, • Added parameter ΔF125. • Removed I_{DDSIRC} • In Table 21, removed I_{LPO} • Updated section: Flash memory module (FTFC) electrical specifications • In section: 12-bit ADC operating conditions, • Updated TBDs for I_{DDA_ADC} and TUE in Table 28 • Updated TBDs for I_{DDA_ADC} and TUE in Table 29 • In section: QuadSPI AC specifications, updated figure 'QuadSPI output timing (HyperRAM mode) diagram'. • In section: 12-bit ADC operating conditions, updated Table 27. • In section: CMP with 8-bit DAC electrical specifications, added note 'For comparator IN signals adjacent ... ' • In table: Table 32, minor update in footnote 6. • In table: Table 41, updated specifications for S32K146.
5	06 Dec 2017	• Removed S32K148 from 'Caution' • Updated figure: S32K1xx product series comparison for • 'EEPROM emulated by FlexRAM' of S32K148 (Added content to footnote) • Added support for LIN protocol version 2.2 A • In Absolute maximum ratings : • Added note 'Unless otherwise ... ' • Added parameter 'Added note 'T_{ramp_MCU}' • Updated footnote for 'T_{ramp}' • In Voltage and current operating requirements : • Added footnote 'V_{DD} and V_{DDA} must be shorted ... ' against parameter 'V_{DD}– V_{DDA}' • Updated footnote 'V_{DD} and V_{DDA} must be shorted ...' • In Power and ground pins • Added diagrams for 32-QFN and 48-LQFP and footnote below the diagrams. • Updated footnote 'V_{DD} and V_{DDA} must be shorted ...' • In Power mode transition operating behaviors :

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Table 43. Revision History

Rev. No.	Date	Substantial Changes

		• Added footnote 'For S32K11x – FIRC/SOSC/FIRC/LPO; For S32K14x – FIRC/SOSC/FIRC/LPO/SPLL' to 'VLPS Mode: All clock sources disabled'
		• Updated numbers for:
		  • VLPR → VLPS
		  • VLPS → VLPR
		  • 'RUN → Compute operation'
		  • RUN → VLPS
		  • RUN → VLPR
		• In Power consumption :
		  • Updated specs for S32K142, S32K144, and S32K148
		  • Updated footnote 'Typical current numbers are indicative ...'
		  • Updated footnote 'The S32K148 data ...'
		  • Removed footnote 'Above S32K148 data is preliminary targets only'
		  • Added new table 'Power consumption at 3.3 V'
		• In General AC specifications :
		  • Updated max value and footnote of WFRST
		  • Updated symbol for not filtered pulse to 'WNFRST', updated min value, removed max. value, and added footnote
		• Fixed naming conventions to align with DS in DC electrical specifications at 3.3 V Range and DC electrical specifications at 5.0 V Range
		• Updated specs for AC electrical specifications at 3.3 V range and AC electrical specifications at 5 V range
		• In Device clock specifications :
		  • Updated f_{BUS} to 48 for 11x
		  • Added footnote to f_{BUS} for 14x
		• In External System Oscillator frequency specifications :
		  • Added specs for S32K11x
		  • Updated 't_{dc_extal}' for S32K14x
		  • Added footnote 'Frequecies below ... ' to 'f_{ec_extal}' and 't_{dc_extal}'
		• Splitted Flash timing specifications — commands for S32K14x and S32K11x
		• Updated Flash timing specifications — commands for S32K14x
		• In Reliability specifications :
		  • Added footnote 'Data retention period ... ' for 'tnvmretp1k' and 'tnvmretee'
		  • Minor update in footnote for 'nnvmwree16' 'nnvmwree256'
		• In QuadSPI AC specifications :
		  • Updated 'MCR[SCLKCFG[5]]' value to 0
		  • Updated 'Data Input Setup Time' HSRUN Internal DQS PAD Loopback value to 1.6
		  • Updated 'Data Input Setup Time' DDR External DQS min. value to 2
		  • Updated 'Data Input Hold Time' DDR External DQS min. value to 20
		  • Upadted figure 'QuadSPI output timing (SDR mode) diagram' and 'QuadSPI input timing (HyperRAM mode) diagram'
		• In 12-bit ADC electrical characteristics :
		  • Added note 'On reduced pin packages where ... '
		  • Removed max. value of 'I_{DDA_ADC}'
		  • Added note 'Due to triple ... '
		• In 12-bit ADC operating conditions, removed parameter 'ΔV_{DDA}'
		• In CMP with 8-bit DAC electrical specifications :
		  • Updated Typ. and Max. values of 'I_{DDLS}'
		  • Upadted Typ. value of 't_{DHSB}'
		  • Updated Typ. value of 'V_{HYST1}' , 'V_{HYST2}', and 'V_{HYST3}'
		• In LPSPI electrical specifications :
		  • Updated 'f_{periph}' and 'f_{op}', and 't_{SPSCK}'

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